

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$ $T_j = 25^\circ\text{C}$			500	μA
		$V_{GS} = 0V, V_{DS} = 80V$ $T_j = 125^\circ\text{C}$			2000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 275A$		1.5	1.6	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 12\text{mA}$	2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			± 450	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		60		nF
C_{oss}	Output Capacitance	$V_{DS} = 25V$		23		
C_{rss}	Reverse Transfer Capacitance	$f = 1\text{MHz}$		8.8		
Q_g	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 50V$ $I_D = 550A$		2100		nC
Q_{gs}	Gate – Source Charge			360		
Q_{gd}	Gate – Drain Charge			1080		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching $V_{GS} = 15V$ $V_{Bus} = 66V$ $I_D = 550A$ $R_G = 1\Omega$		185		ns
T_r	Rise Time			270		
$T_{d(off)}$	Turn-off Delay Time			600		
T_f	Fall Time			175		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 550A, R_G = 1\Omega$		3.3		mJ
E_{off}	Turn-off Switching Energy			3.6		
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 550A, R_G = 1\Omega$		3.65		mJ
E_{off}	Turn-off Switching Energy			3.85		

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_S	Continuous Source current (Body diode)	$T_c = 25^\circ\text{C}$			860*	A
		$T_c = 80^\circ\text{C}$			640*	
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -550A$			1.3	V
dv/dt	Peak Diode Recovery ❶				5	V/ns
t_{rr}	Reverse Recovery Time	$I_S = -550A$ $V_R = 66V$ $di/dt = 600A/\mu\text{s}$	$T_j = 25^\circ\text{C}$		190	ns
			$T_j = 125^\circ\text{C}$		370	
Q_{rr}	Reverse Recovery Charge	$I_S = -550A$ $V_R = 66V$ $di/dt = 600A/\mu\text{s}$	$T_j = 25^\circ\text{C}$	2.4		μC
			$T_j = 125^\circ\text{C}$	10.2		

❶ dv/dt numbers reflect the limitations of the circuit rather than the device itself.

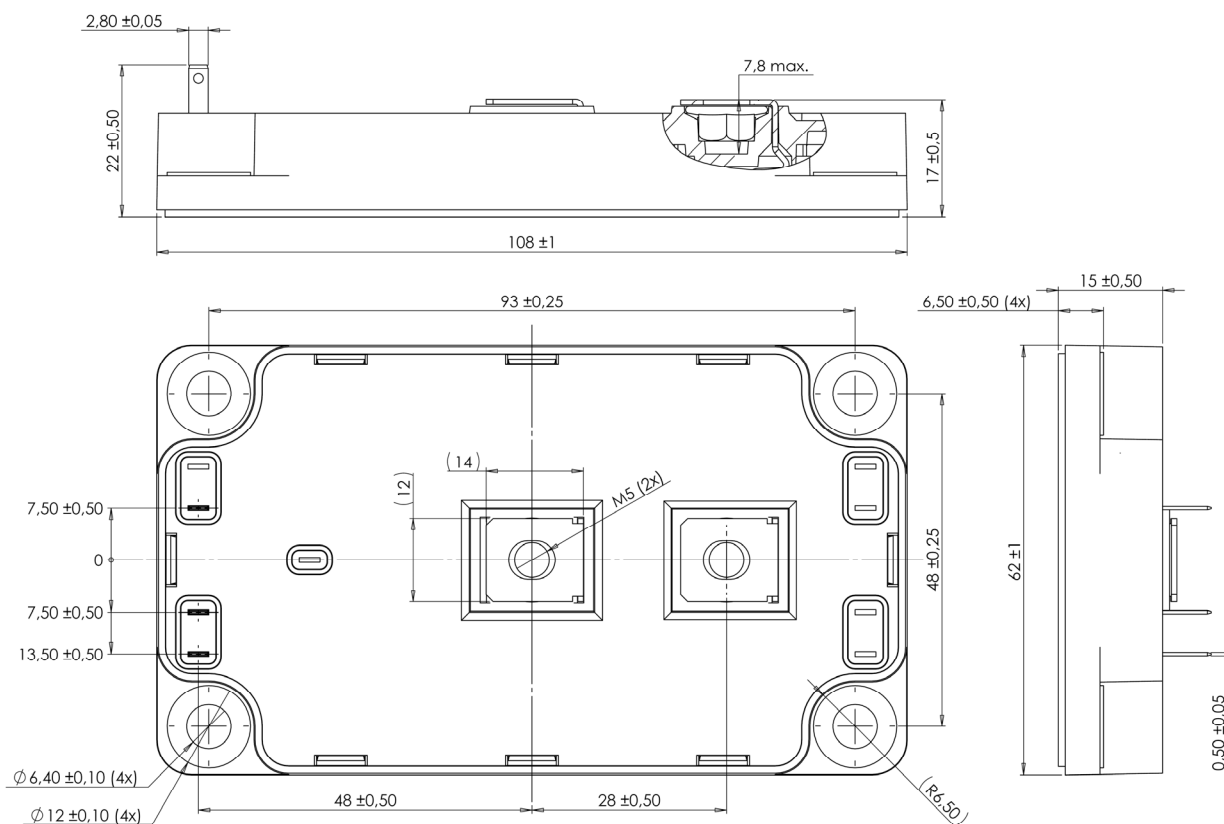
$I_S \leq -860A$ $di/dt \leq 600A/\mu\text{s}$ $V_R \leq V_{DSS}$ $T_j \leq 150^\circ\text{C}$



<i>Symbol</i>	<i>Characteristic</i>
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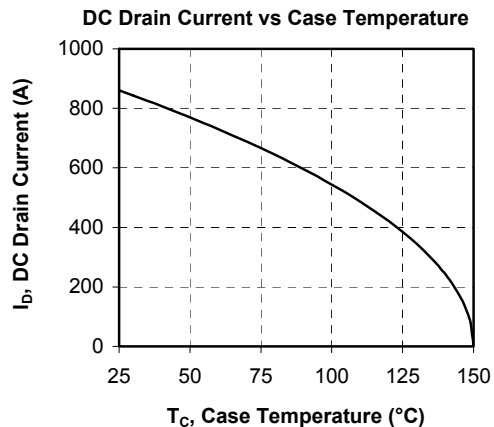
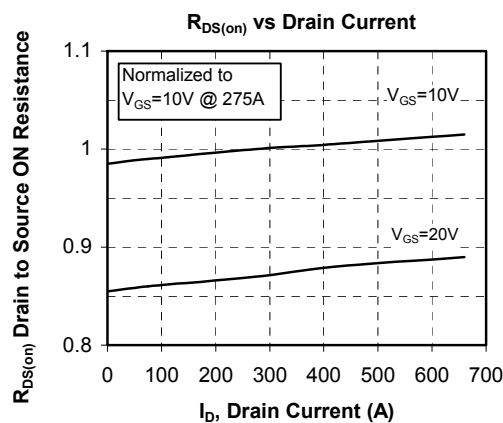
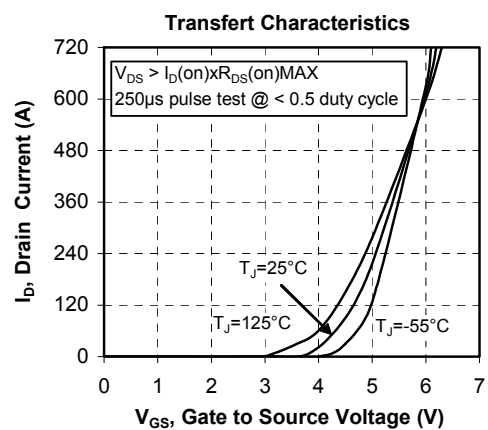
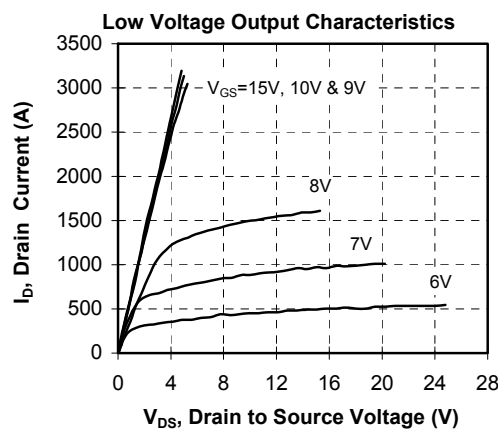
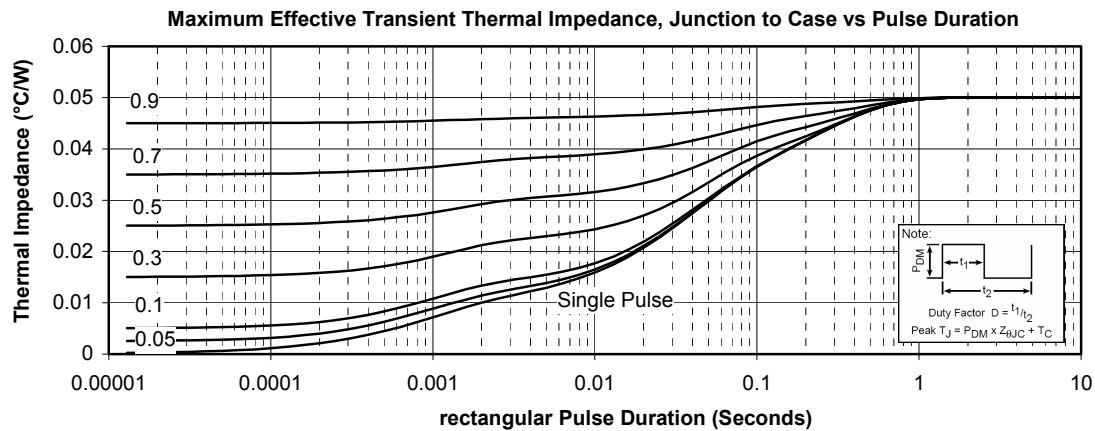
Symbol	Characteristic	Min	Typ	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance			0.05	°C/W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz	4000			V
T _J	Operating junction temperature range	-40		150	°C
T _{STG}	Storage Temperature Range	-40		125	
T _C	Operating Case Temperature	-40		100	
Torque	Mounting torque	To heatsink	M6	3	N.m
		For terminals	M5	2	
Wt	Package Weight			300	g

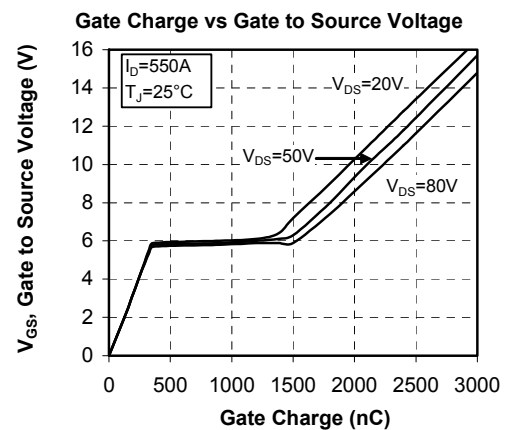
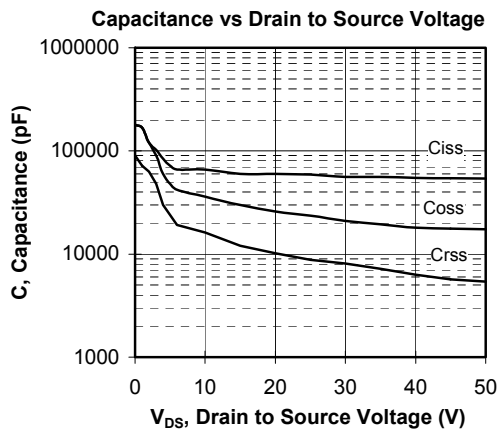
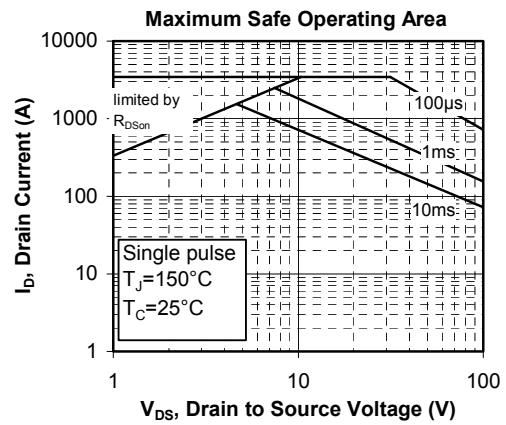
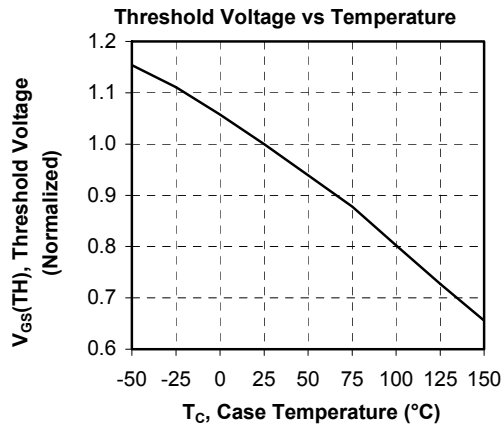
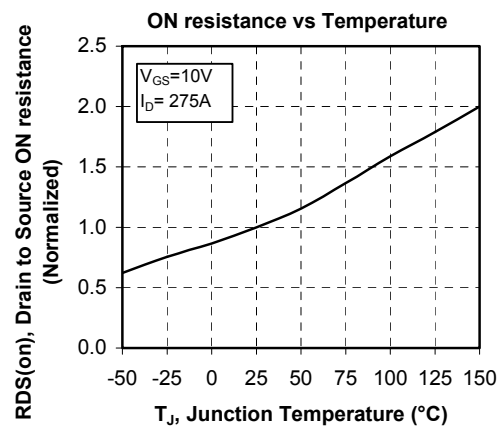
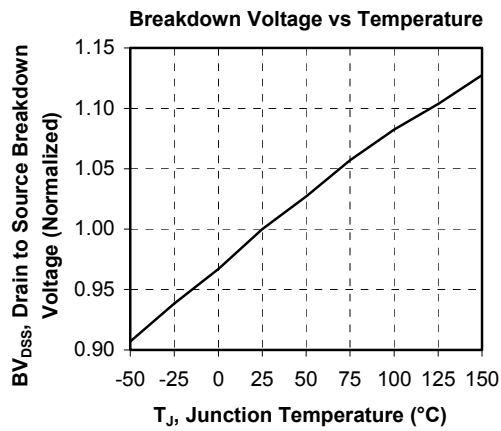
SP6 Package outline (dimensions in mm)



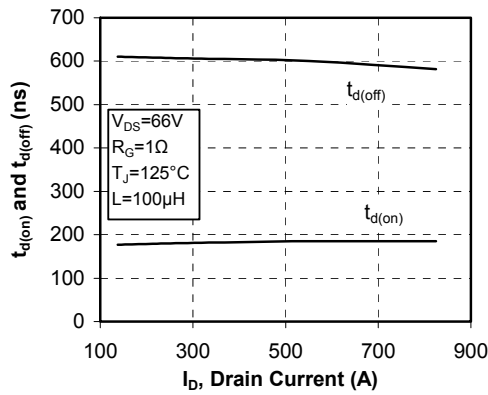
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve

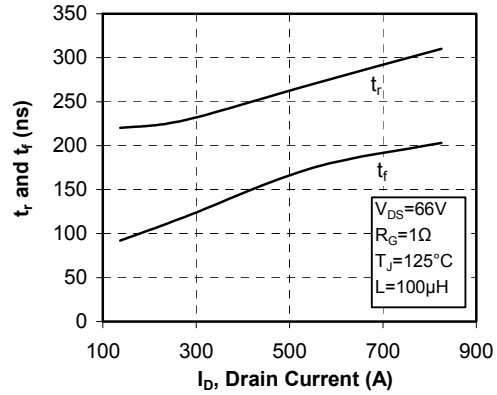




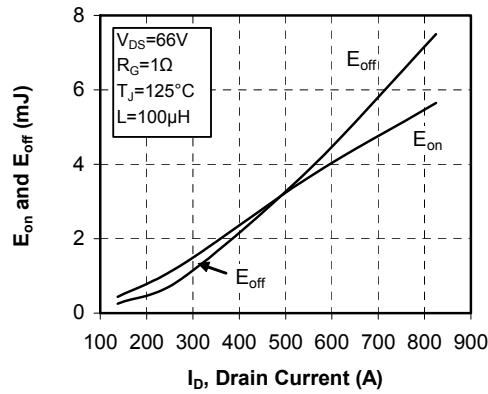
Delay Times vs Current



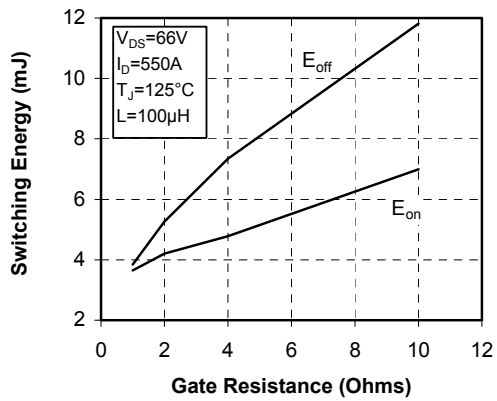
Rise and Fall times vs Current



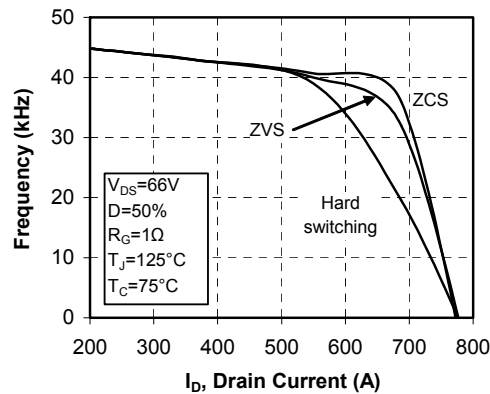
Switching Energy vs Current



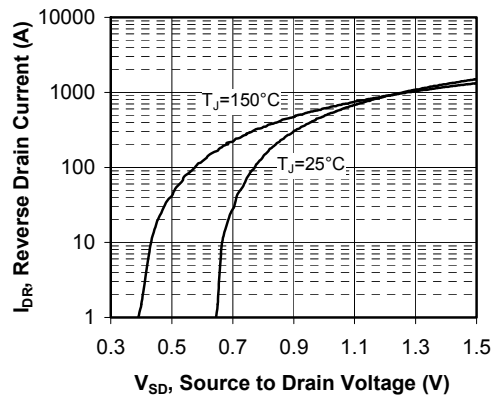
Switching Energy vs Gate Resistance



Operating Frequency vs Drain Current



Source to Drain Diode Forward Voltage



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